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NX7338BF-AA

Data Sheet

R08DS0004EJ0400 Rev.4.00 Feb 28, 2011

LASER DIODE

1 310 nm InGaAsP MQW-FP LASER DIODE COAXIAL MODULE FOR OTDR APPLICATION

DESCRIPTION

The NX7338BF-AA is a 1 310 nm Multiple Quantum Well (MQW) structured Fabry-Perot (FP) laser diode coaxial module with single mode fiber. This module is specified to operate under pulsed condition and designed for light source of Optical Time Domain Reflectometer (OTDR).

FEATURES

• High output power $P_f = 110 \text{ mW} @ I_{FP} = 400 \text{ mA}^{*1}$

• Long wavelength $\lambda c = 1310 \text{ nm}$

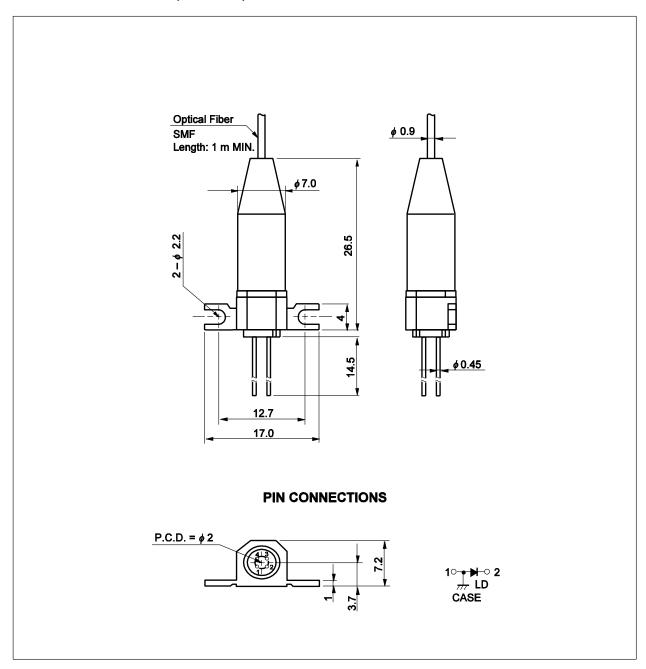
*1 Pulse Conditions: Pulse width (PW) = 10 μ s, Duty = 1%



The mark <R> shows major revised points.

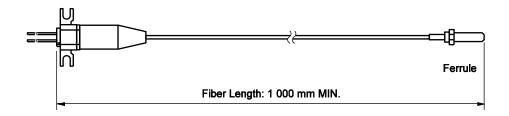
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

<R> PACKAGE DIMENSIONS (UNIT: mm)



OPTICAL FIBER CHARACTERISTICS

Parameter	Specification	Unit
Mode Field Diameter	9.3±0.5	μm
Cladding Diameter	125±2	μm
Maximum Cladding Noncircularity	2	%
Maximum Core/Cladding Concentricity	1.6	%
Outer Diameter	0.9±0.1	mm
Cut-off Wavelength	1 140 to 1 280	nm
Minimum Fiber Bending Radius	30	mm
Fiber Length	1 000 MIN.	mm



ORDERING INFORMATION

Part Number	Flange Type	
NX7337BF-AA	flat mount flange	

ABSOLUTE MAXIMUM RATINGS

Parameter Symbol		Ratings	Unit
Pulsed Forward Current*1 IFP		600	mA
Reverse Voltage	VR	2.0	V
Operating Case Temperature	Tc	-20 to +60	°C
Storage Temperature	T _{stg}	-40 to +85	°C
Lead Soldering Temperature	Tsld	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

^{*1} Pulse Condition: Pulse Width (PW) = 10 μ s, Duty = 1%

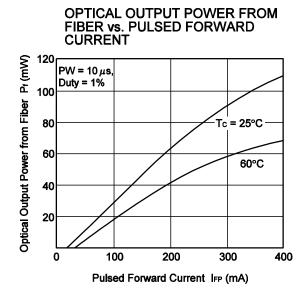
ELECTRO-OPTICAL CHARACTERISTICS (Tc = 25°C)

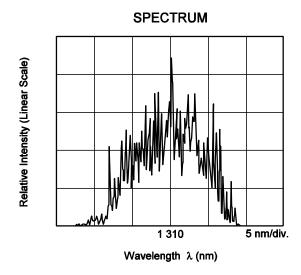
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Forward Voltage	VFP	I _{FP} = 400 mA, PW = 10 μs, Duty = 1%		2.5	4.0	V
Threshold Current	Ith			20	30	mA
Optical Output Power from Fiber	Pf	IFP = 400 mA, PW = 10 μs, Duty = 1%	70	110		mW
Center Wavelength	λς	RMS (-20 dB), I _{FP} = 400 mA, PW = 10 \(\mu\)s, Duty = 1%	1 290	1 310	1 330	nm
Spectral Width	σ	RMS (-20 dB), I _{FP} = 400 mA, PW = 10 µs, Duty = 1%		4.5	10.0	nm
Rise Time	tr	10-90%			2.0	ns
Fall Time	t f	90-10%			2.0	ns

ELECTRO-OPTICAL CHARACTERISTICS (Tc = 0 to +60°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Threshold Current	Ith				50	mA
Optical Output Power from Fiber	Pf	IFP = 400 mA, PW = 10 μs, Duty = 1%	50			mW
Center Wavelength	λς	RMS (-20 dB), I _{FP} = 400 mA, PW = 10 \(\mu\)s, Duty = 1%	1 280		1 342.5	nm
Temperature Dependency of Center Wavelength	Δλ/ΔΤ			0.35		nm/°C
Spectral Width	σ	RMS (-20 dB), I _{FP} = 400 mA, PW = 10 <i>µ</i> s, Duty = 1%			10	nm

TYPICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)





Remark The graphs indicate nominal characteristics.

REFERENCE

Document Name	Document No.	
Opto-Electronics Devices Pamphlet *1	PX10160E	

^{*1} Published by the former NEC Electronics Corporation.

SAFETY INFORMATION ON THIS PRODUCT





Warning Laser Beam	A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.
	Do not look directly into the laser beam.
	Avoid exposure to the laser beam, any reflected or collimated beam.
Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	Do not lick the product or in any way allow it to enter the mouth.
Caution Optical Fiber	A glass-fiber is attached on the product. Handle with care. When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.

RENESAS

Revision History

NX7338BF-AA Data Sheet

			Description		
Rev.	Date	Page	Summary		
_	Jul 2006	_	Previous No.: PL10603EJ02V0DS		
3.00	Sep 19, 2010	p.1	Modification of photograph		
		p.2, 3	Modification of PACKAGE DIMENSIONS		
4.00	Feb 28, 2011	p.2	Modification of PACKAGE DIMENSIONS : MMF -> SMF		